**Advanced Materials and Devices for Bioresorbable Electronics**

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**CONSPECTUS:** Recent advances in materials chemistry establish the foundations for unusual classes of electronic systems, characterized by their ability to fully or partially dissolve, disintegrate, or otherwise physically or chemically decompose in a controlled fashion after some defined period of stable operation. Such types of “transient” technologies may enable consumer gadgets that minimize waste streams associated with disposal, implantable sensors that disappear harmlessly in the body, and hardware-secure platforms that prevent unwanted recovery of sensitive data. This second area of opportunity, sometimes referred to as bioresorbable electronics, is of particular interest due to its ability to provide diagnostic or therapeutic function in a manner that can enhance or monitor transient biological processes, such as wound healing, while bypassing risks associated with extended device load on the body or with secondary surgical procedures for removal.

Early chemistry research established sets of bioresorbable materials for substrates, encapsulation layers, and dielectrics, along with several options in organic and bio-organic semiconductors. The subsequent realization that nanoscale forms of device-grade monocrystalline silicon, such as silicon nanomembranes (m-Si NMs, or Si NMs) undergo hydrolysis in biofluids to yield biocompatible byproducts over biologically relevant time scales advanced the field by providing immediate routes to high performance operation and versatile, sophisticated levels of function. When combined with bioresorbable conductors, dielectrics, substrates, and encapsulation layers, Si NMs provide the basis for a broad, general class of bioresorbable electronics. Other properties of Si, such as its piezoresistivity and photovoltaic properties, allow other types of bioresorbable devices such as solar cells, strain gauges, pH sensors, and photodetectors. The most advanced bioresorbable devices now exist as complete systems with successful demonstrations of clinically relevant modes of operation in animal models.

This Account highlights the foundational materials concepts for this area of technology, starting with the dissolution chemistry and reaction kinetics associated with hydrolysis of Si NMs as a function of temperature, pH, and ion and protein concentration. A following discussion focuses on key supporting materials, including a range of dielectrics, metals, and substrates. As comparatively low performance alternatives to Si NMs, bioresorbable organic semiconductors are also presented, where interest derives from their intrinsic flexibility, low-temperature processability, and ease of chemical modification. Representative examples of encapsulation materials and strategies in passive and active control of device lifetime are then discussed, with various device illustrations. A final section outlines bioresorbable electronics for sensing of various biophysical parameters, monitoring electrophysiological activity, and delivering drugs in a programmed manner.

Fundamental research in chemistry remains essential to the development of this emerging field, where continued advances will increase the range of possibilities in sensing, actuation, and power harvesting. Materials for encapsulation layers that can delay water-diffusion and dissolution of active electronics in passively or actively triggered modes are particularly important in addressing areas of opportunity in clinical medicine, and in secure systems for envisioned military and industrial uses. The deep scientific content and the broad range of application opportunities suggest that research in transient electronic materials will remain a growing area of interest to the chemistry community.

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**INTRODUCTION**

Transient electronics is an emerging class of technology characterized by constituent materials that are fully or partially dissoluble or disintegrable by chemical or physical processes, as
means to eliminate their existence after a defined period of operation. Application opportunities focus on areas where conventional electronics cannot address key requirements. Examples include environmentally degradable consumer devices that minimize unwanted waste and hardware-oriented secure platforms that physically remove sensitive information or device designs. The most compelling area might be in bioresorbable electronics, as the basis for active implants that provide diagnostic or therapeutic function during a biological process, such as wound healing, and then disappear entirely to circumvent the need for surgical removal. This natural process of resorption eliminates risk associated with the long-term presence of implantable devices, where infections, immune responses, and steric obstructions represent a few of the many possible types of

Figure 1. Dissolution chemistry and kinetics of hydrolysis of Si NMs in various aqueous environments. (a) Series of topographical images of a Si NM during hydrolysis in p-PBS. Reproduced with permission from ref 1. Copyright 2012 AAAS. (b) Dissolution kinetics of a Si NM in buffer solutions with various pH at room temperature (left) and body temperature (right, 37 °C) expressed in thickness change. Reproduced with permission from ref 2. Copyright 2014 Wiley. (c) Hydrolysis kinetics of a Si NM in aqueous solution with various concentrations of potassium phosphates at 37 °C. Reproduced with permission from ref 15. Copyright 2015 Wiley. (d) Dependence of the dissolution of Si NMs on the presence of Si(OH)4 with different protein concentrations. Reproduced with permission from ref 16. Copyright 2017 American Chemical Society. (e) Dopant concentration dependent dissolution of a Si NM in phosphate buffer solution at 37 °C. Reproduced with permission from ref 35. Copyright 2014 American Chemical Society. (f) Dissolution kinetics of poly-Si, a-Si, SiGe, and Ge in buffer solution with different pH at 37 °C. Reproduced with permission from ref 21. Copyright 2015 American Chemical Society.
complications.7 Procedures in surgical extraction have their own risks.8 Biodegradable electronics thereby provide the ultimate solution, where therapeutic function can be analogous to, but distinctly different from, pharmacological approaches to treating disease.

The earliest exploratory efforts in biodegradable electronics, which included successful demonstrations in animal models, used nonresorbable but thin and ultraminiaturized inorganic electronic components supported by and embedded in biodegradable polymer materials.9 Subsequent research examined the possibility of devices built with biodegradable organic semiconductors, both synthetic and naturally occurring materials, and nonresorbable metals.10–12 The realization that device-grade m-Si nanomembranes (NMs) can undergo hydrolysis to yield benign end products in biofluids established a set of opportunities in high performance classes of electronic systems with versatile functionality.

This Account summarizes recent research efforts in this area, with a focus on these materials and associated underlying chemical processes of resorption, but also with several examples of relevance to biomedical device technology. Some concluding remarks address areas for future work.

■ CHEMISTRY OF DISSOLUTION OF SILICON NANOMATERIALS

Monocrystalline, electronic-grade silicon is considered to be chemically stable in ambient aqueous environments, due partly to the spontaneous formation of a native oxide on its surface. This notion of stability depends, however, on structural dimensions and observational time scales. Specifically, loss of material from the surface of a bulk silicon wafer (∼1 mm thick) immersed in water at rates of a few nanometers per day can be neglected over laboratory time scales; such rates of loss for silicon nanowires, nanoribbons, or nanomembranes will lead to their complete disappearance during similar time frames.1 In the context of systems described in this Account, active silicon surfaces suggest that the most important reaction is hydrolysis in minute changes to this naturally occurring background level. Since the silicon surface terminates Si atoms on the surface. Since the silicon surface is chemically stable in ambient aqueous environments, due partly to the introduction of ions into the surrounding aqueous solutions. The chemical complexity increases considerably upon introduction of ions into the surrounding aqueous solutions. As summarized in Figure 1c, certain ions significantly accelerate the rates of reaction,13 including those (e.g., Na+, Ca2+, and Mg2+ cations and Cl−, HCO3−, HPO4− anions) that are common in environmental and biological fluids at concentrations from 0.1 to >50 g/L. The data show that Si NMs dissolve at ∼1 nm/day in low ionic concentrations (e.g., 0.05 M K2HPO4/KH2PO4) and up to 65 nm/day at high concentrations (e.g., 1 M K2HPO4/KH2PO4). These variations arise from catalyzing effects of the ions, as suggested by density functional theory (DFT) for the case of anions (HPO42− or Cl−) where interactions with surface Si atoms can weaken nearby Si–Si backbones.14 Other simulated biological solutions show different results. For example, remarkably high rates of dissolution (20 to 100 nm/day) occur in bovine serum,15,16 modulated by divalent cations (∼1 mM Mg2+, Ca2+) and various proteins (∼50 g/L in total).17 Separate experiments designed to reveal the various effects show that CaCl2 (1 mM) and albumin (35 g/L) in p-PBS increase by ∼50% and decrease by ∼30% the rate of dissolution, respectively.18 The latter effect likely arises from adsorption of protein on the silicon surface (0.5 to 1.5 nm, depending on type of protein).19 The role of silicic acid (Si(OH)4) as a product of dissolution and a ubiquitous component of natural and biological fluids is also important in this context, as summarized in Figure 1d with three different albumin concentrations in p-PBS.20 The results show an increased dependence of the dissolution rate on [Si(OH)4] with reduced protein concentration, that is, for 0.01 g/L albumin, S9 ±0.5 to 39 ±1.9 nm/day and for 35 g/L albumin, 39 ±0.4 to 33 ±1.1 nm/day. The dependence on [Si(OH)4] can be attributed to reduced step propagation rates and increased activation energy for the formation of vacancy (or highly reactive) sites where dissolution starts to spread.21 Dopants in the silicon also affect the reaction chemistry. Figure 1e summarizes the rates of dissolution of Si NMs with boron (p-type) dopants at concentrations from 1017 to 1020 cm−3 in phosphate buffer solution (0.1 M, pH 7.4). The rates remain unchanged for concentrations up to 1019 cm−3 and decrease significantly at 1020 cm−3 and above. Similar behavior results
from doping with phosphorus (n-type). Such effects are well-known in silicon etching, and they serve as etch stop strategies for chemical micromachining in solutions of KOH (10−57%) or ethylenediamine. The underlying chemistry follows mainly from differences in the native oxide layer that spontaneously forms on the silicon surface. Specifically, ellipsometric measurements show stable, dense layers (∼1 nm) of SiO₂ on highly doped Si (both boron and phosphorus) when immersed in water, possibly due to barrier-less oxidation pathways facilitated by the presence of dopants or lattice strains induced by the different atomic sizes of silicon and dopants. Lightly doped Si, by comparison, exhibits porous surface layers of SiO₂ that grow in parallel with dissolution of Si. The rate of dissolution of SiO₂ is much slower than that of Si, thereby providing a plausible chemical explanation for the variation in rate with doping level. Additional forms silicon can also be dissoluble. Figure 1f summarizes the dissolution kinetics of poly-Si, a-Si, Ge, and SiGe in phosphate buffer solution (pH 7.4, 0.1 M, 37 °C).

**OTHER DISSOLVABLE ELECTRONIC MATERIALS**

Recent work shows that Mg, Zn, W, and Mo can serve as bioresorbable metals; systematic studies reveal their dissolution
behavior in thin films and foils. These metals react according to Mg + 2H₂O → Mg(OH)₂ + H₂, Zn + 2H₂O → Zn(OH)₂ + H₂, 2W + 2H₂O + 3O₂ → 2H₂WO₄, 2Mo + 2H₂O + 3O₂ → 2H₂MoO₄. Fe can dissolve to form hydroxides (Fe(OH)₂ and Fe(OH)₃), although certain byproducts such as Fe₂O₃ and Fe₃O₄ have very low solubility and lead to irregular dissolution.

Metallic alloys such as those based on Mg and Zn (AZ31B) create possibilities for tunable dissolution. The dissolution rates of Mg, Zn, W, Mo, and AZ31B in a representative biofluid (Hank’s solution) are 7 × 10⁻⁵, 7 × 10⁻³, (1.7–0.3) × 10⁻³, 3 × 10⁻⁴, and 2 × 10⁻² μm h⁻¹ at room temperature.23

Silicon oxides and nitrides represent attractive choices for biodegradable dielectrics and encapsulants. For example, p- and n-type metal oxide semiconductor field-effect transistors (MOSFETs) constructed with Si NM channels (300 nm thick), SiO₂ gate dielectric (50 nm thick), and Mg electrodes (300 nm thick) show on/off ratios of greater than ~10⁵ and mobilities of ~70 and ~400 cm² V⁻¹ s⁻¹, respectively.24 Some unusual choices for dielectrics in biodegradable systems include egg albumen and magnesium difluoride.25,26

Demonstrated substrates for these applications include thin metal foils and films of polymers (silks, polycaprolactone (PCL), polylactic acid) (PLA), poly(lactic-co-glycolic acid) (PLGA, a blend of poly(lactic acid) (PLA) and poly(glycolic acid) (PGA)), and even foodstuffs (rice paper, cheese, seaweed).25,26,31 The substrate also can serve as a water barrier. Some of the most important opportunities are in new materials for substrates and encapsulation layers. Examples of encapsulation strategies follow in later sections.

### BIOCOMPATIBILITY OF SI NANOMEMBRANES AND OF THEIR DISSOLUTION PRODUCTS

The biocompatibility of Si NMs and hydrolysis byproducts is critically important. Studies of np-Si, which dissolves by the same chemistry but at much higher rates than m-Si, yield some insights.33,34 The main product, silicic acid, is a nontoxic small molecule that can be absorbed by the gastrointestinal tract and is excreted via the urine.34

Separate studies of the biocompatibility of Si NMs support similar conclusions. When present in cell cultures (metastatic breast cancer cell line (MDA-MB-231)), viability remains above 93% throughout the complete dissolution process.35 Animal model (mice) studies that use Si NMs on silk substrates as subdermal implants indicate no change of body weight and no additional generation of primary immune cells from the axillary and brachial draining lymph nodes. Related biocompatibility research involves Si NMs with other transient materials, such as Mg, SiO₂, and PLGA in the form of functional devices and test platforms. In one case, pressure sensors implanted into the intracranial space of rat models for 2, 4, and 8 weeks indicate no overt reactions of brain glial cells and no focal aggregation of glial cells. Astrocytosis (an increase in the number of astrocyte cells) and microglial activity at the cortical surface remain within normal limits, indicating no overt immune reaction to the device or its byproducts.4

### ALTERNATIVE BIORESORBABLE SEMICONDUCTORS: ORGANIC POLYMERS

Although Si NMs enable excellent performance characteristics, organic semiconductors offer complementary features such as low-temperature synthesis and processing, comparatively soft/flexible mechanical characteristics, versatile options in surface modification for sensing, and chemically tailored rates of dissolution. Naturally occurring materials provide some interesting options. Figure 2a shows biodegradable organic thin-film transistors (OTFTs) formed with 5,5'-bis-(7-dodecyl-9H-fluoren-2-yl)-2,2'-bithiophene (DDFTFT), poly(vinyl alcohol) (PVA), and PLGA as semiconductor, dielectric, and substrate, respectively with Au and Ag electrodes. Although the chemistry associated with its degradation is not well-known, the reactions are likely similar to those for the decomposition of melanin, 5,6-Dihydroxyindole melanin degrades to pyrrole-2,3,5-tricarboxylic acid and pyrrole-2,3,5-dicarboxylic acid. OTFTs built with these materials can exhibit mobilities up to ~0.25 cm² V⁻¹ s⁻¹ and on/off current ratios up to 9 × 10⁴.

Figure 2b provides an additional example in the form of ambipolar field effect transistors built using indigo, a thin layer of Al₂O₃ passivated with tetraetracontane, shellac, and Au for semiconductor, dielectric, substrate, and electrode, respectively. Indigo, a dye obtained from the plants Indigofera tinctoria and Isatis tinctoria, has strong inter- and intramolecular hydrogen bonding and intramolecular π interactions that yield semiconducting properties. The layer of tetratoctacontane (C₄₄H₉₀, TTC) has interactions with the indigo that are favorable for interfacial charge transport. The mobilities for electrons and holes are 1 × 10⁻⁴ cm² V⁻¹ s⁻¹ and 5 × 10⁻² cm² V⁻¹ s⁻¹, respectively. The indigo naturally degrades slowly with the passing of time under the effect of light, humidity, and oxidizing agents.36,37 Other natural materials include indanthrene yellow G (vat yellow 1), indanthrene brilliant orange RF (vat orange 3), and perylene diimide as semiconductors and nucleobases (adenine and guanine), sugars (glucose, lactose, sucrose) or caffeine as dielectrics.38

Specially synthesized polymers can offer improved properties. Figure 2c shows the chemical structure of the polymer PDPP−PD, as synthesized by a condensation reaction between phenylenediamine and DPP−CHO, which is formed by two aldehyde groups to diketopyrrolopyrrole (DPP) at ~77 °C with catalysis (p-toluenesulfonic acid (PTSA)). Reaction of succinic aldehyde groups to diketopyrrolopyrrole (DPP) at ~77 °C with catalysis (p-toluenesulfonic acid (PTSA)). Reaction of succinic aldehyde groups to diketopyrrolopyrrole (DPP) at ~77 °C with catalysis (p-toluenesulfonic acid (PTSA)). Reaction of succinic aldehyde groups to diketopyrrolopyrrole (DPP) at ~77 °C with catalysis (p-toluenesulfonic acid (PTSA)).
mosfets described previously, electrical double-layer transistors, resistive switching memories, complementary metal oxide semiconductor (cmos), logic circuits, and others are also possible. figure 3a highlights results from one of the earliest circuit examples, in which a complete set of active (diode, transistor) and passive (inductor, capacitor, resistor) devices based on si nm, mg, mgO, and silks form a colpitts oscillator on a thin film of silk fibroin. each constituent material dissolves in aqueous solutions with characteristic kinetics defined by the chemistry. figure 3b shows si cmos three-stage ring oscillators formed with similar materials and powered by scavenging circuits, as an additional illustration of the level of complexity that is possible using academic laboratory facilities.
etching of the handle wafer of a silicon on insulator (SOI) substrate and manipulation of the released components by transfer printing represent critical steps toward integration with transient substrates.

Encapsulation strategies are critically important to enable reliable operation for a defined time frame. Figure 3d shows an example of the type of two-stage operation that occurs as a result, for the case a N-MOSFET encapsulated with a bilayer of MgO and crystallized silk during immersion in water: stable operation and then rapid degradation after water penetration. This strategy for controlling the functional lifetime relies critically on reproducible materials properties and absence of structural defects such as pinholes or variability in molecular chemistry or morphology. The development of new materials for this purpose and of strategies for time-triggered transient systems represent areas of current interest.

Functional transient materials, together with specialized device designs and fabrication strategies, allow access to many types of sensors, actuators, and energy-storage devices. Demonstrated examples of the first device type include thermoactive temperature gauges and sensors of thermal transport characteristics, as well as capacitive-type humidity sensors that use Si NM electrodes, Mg interconnects, and PLGA substrates; mechanical sensors such as piezoresistive strain gauges, pressure sensors, accelerometers, photodiode imagers, and chemical sensors. Figure 4a shows examples of pH sensors that use stretchable ion-sensitive FETs and serpentine interconnecting electrodes on elastic polymer substrates.

Transient energy sources are essential for many envisioned applications, including remote monitoring devices and biomedical implants. Figure 4b–e summarizes some options, from batteries and supercapacitors to energy harvesters. Galvanostatic pairs of biosorbable metals such as Mg/Mo (Figure 4b) can provide electrochemical sources of electrical power when immersed in electrolyte solution. The performance of single cell batteries that consist of Mg−X (X = Fe, W, or Mo) metal foils with PBS as the electrolyte can yield constant discharge current densities (0.1 mA cm⁻²) and operating voltages of ~0.75, ~0.65,
and ∼0.45 V for Fe, W, and Mo, respectively. Stacking individual Mg–Mo cells in series can increase the output voltage up to 1.6 V (4 stacking cells) and beyond. The main electrochemical reactions are as follows:

Figure 5. Biomedical applications of bioresorbable devices. (a) Image of bioresorbable pressure and temperature sensors integrated with dissolvable metal (Mo) interconnects. Reproduced with permission from ref 4. Copyright 2016 Nature Publishing Group. (b) Diagram of a bioresorbable temperature and pressure sensor in the intracranial space of a rat model (left). Injectable form of pressure sensor for deep brain monitor (right, upper). Wireless operation of pressure sensor with percutaneous wiring (right, lower). Reproduced with permission from ref 4, Copyright 2016 Nature Publishing Group. (c) Structure and image of a bioresorbable actively multiplexed sensing system. Reproduced with permission from ref 5. Copyright 2016 Nature Publishing Group. (d) Structure and image of bioresorbable electronic stent with multifunctional devices of temperature and flow sensors, memory modules, and therapeutic nanoparticles. Reproduced with permission from ref 47. Copyright 2015 American Chemical Society. (e) Injection (∼5 μL) of Staphylococcus aureus at the device implantation site to mimic surgical-site infections and heat treatments for anti- (left). Reproduced with permission from ref 6. Copyright 2014 National Academy of Sciences. (f) Bioresorbable, wirelessly programmable drug delivery device that exploits thermally activated lipid membranes (right). Reproduced with permission from ref 48. Copyright 2015 Nature Publishing Group. Inductive coil based microheaters formed with Si resistor, Mg electrode, and MgO dielectric on silk (e) and Mo resistor and electrode and PLGA dielectric and substrate (f).
Anode:

\[ \text{Mg} \rightarrow \text{Mg}^{2+} + 2e^- \]

Cathode:

\[ \text{O}_2 + 2\text{H}_2\text{O} + 4e^- \rightarrow 4\text{OH}^- \quad (\text{oxygen reduction}) \]

or \[ 2\text{H}_2\text{O} + 2e^- \rightarrow \text{H}_2 + 2\text{OH}^- \]

(hydrogen evolution)

Other bioresorbable batteries use only organic materials (cellulose membranes, carbon paper electrodes, beeswax impermeable coatings, and organic redox species). In one case, oxalic acid (\(\text{C}_2\text{H}_2\text{O}_4\)) and KOH serve as the supporting electrolyte for the positive and negative half-cells, respectively. Prototype devices operate for up to 100 min with an output voltage that can be scaled to match the needs of portable electronic devices (1.5–3.0 V). All materials undergo ~50% biodegradation in anaerobic conditions after 60 days.

Microsupercapacitors (MSCs), as highlighted in Figure 4c, represent complementary technologies for energy storage. Bioresorbable MSCs consist of water-soluble metal (W, Fe, and Mo) electrodes, a biopolymer hydrogel electrolyte (agarose gel), and a PLGA substrate, encapsulated with polyanhydride. The operation exploits the pseudocapacitance of metal-oxide coatings that result from electrochemical corrosion at the interface between the water-soluble metal electrode and the hydrogel (\(\text{NaCl}/\text{agarose}\)) electrolytes. MSCs with Mo inter-digitated electrodes and a complete set of degradable components offer areal capacitances of 1.6 mF·cm\(^{-2}\), energy density of 0.14 μW·h·cm\(^{-2}\), and power density of 1.0 mW·cm\(^{-2}\).

Transient systems can be designed to capture power from ambient sources. Figure 4d,e shows examples of photovoltaic and piezoelectric systems. Thin layers of m-Si (\(<3 \mu\text{m} \) thick) serve as active materials in solar cells where Mg and silk form the electrodes and substrates (Figure 4d). Overall power conversion efficiencies (\(\eta\)) can reach ~3%, limited by incomplete absorption in the thin silicon, with fill factors of 66%. These results are comparable to those of conventional cell designs in this range of thicknesses, when schemes for light-trapping, backside reflection, or antireflection coatings are not used. Harvesting electrical power from mechanical motions is also possible. Dагdeviren et al. report designs and fabrication schemes for ZnO thin-film mechanical energy harvesters and describe their mechanics and dissolution kinetics. Films of Mg (\(<300–400 \) nm) serve as top and bottom electrodes for a sputter deposited thin film of ZnO (350–500 nm) as the piezoelectric component of the device on a silk substrate. In a typical device, voltage and current outputs can reach ~1.14 V and ~0.35 nA, with a peak output power density of ~10 nW/cm\(^2\). An alternative harvesting approach uses triboelectric effects based on contact between the nanostructured surfaces of biodegradable polymers (e.g., PLGA, PVA, PCL, or poly(3-hydroxybutyric acid-co-3-hydroxyvaleric acid) (PHB/V)), where thin films of Mg (50 nm) provide the electrodes. Outputs from such types of generators (size, 2.0 \times 3.0 \text{ cm}^2) can reach tens of volts.

### BIORESORBABLE ELECTRONIC IMPLANTS

Implantable devices offer diverse and essential functions for research, advanced diagnosis, and treatment. Traditional permanent electronics provide a range of important functions in this context. In certain cases, this function is most valuable for finite periods of time, matched to intrinsic biological processes, such as wound healing. Here, removal of the devices after this time period is required to eliminate unnecessary load on the patient and associated risks of uncontrolled migration within the body, pathological tissue responses, and infection. The surgical retrieval procedures, however, can involve complications themselves. Bioresorbable electronics offer a potential solution in this context. The following summarizes recent research demonstrations.

Figure 5a shows a bioresorbable sensor of intracranial pressure, designed for monitoring recovery following a traumatic injury to the brain. The device incorporates a Si NM piezoresistive strain sensor integrated onto a flexible PLGA membrane that forms the top seal of an underlying cavity created on the etched region of the surface of an np-Si substrate or Mg foil. Figure 5b illustrates its application as an intracranial pressure monitor with an interface to a wireless unit for data transmission. Degradeable wires coated with PLGA provide electrical connections between the sensor and external electronics. Studies using a rodent model indicate stable measurement of temperature and pressure in the intracranial space for 3 days.

Active electronic interfaces to the brain also have utility in this context of monitoring during recovery from an injury. Figure 5c shows passively and actively addressed systems for electrophysiological monitoring on the surface of the brain, where the constituent materials and fabrication strategies are similar to those for the devices in Figure 5a. In these platforms, Si NM electrodes record normal physiologic and epileptiform activity such as electrocorticography (ECoG) and subdural encephalograms (EEG), in both acute and chronic situations. Heavy doping levels in the Si electrodes lead to relatively slow rates of dissolution in biofluids, thereby enabling use for over 33 days. Systems that include transistors offer active multiplexing for high speed, high resolution mapping. Temporary electronic implants with utility in cardiovascular medicine are also possible such as electronically instrumented bioresorbable stents (Figure 5d).

Such devices use a magnesium alloy mechanical structure with flow and temperature sensors (physiological signal sensing), and an resistive random-access memory (RRAM) array (data storage) based on bioresorbable (Mg, MgO, Zn, ZnO, SiO\(_2\), PLA) materials.

These various systems hint at a future in devices with multimodal operational capabilities and broad utility in biomedicine. In this context, the addition of active, therapeutic function is of interest. One of the earliest examples (Figure 5e) used a wireless power delivery scheme for local heating to eliminate bacterial colonies that are either inaccessible or nonresponsive to antibiotic treatments. Such systems, constructed with Mg, MgO, and silk, can be left in the body at the end of an intraoperative period. Figure 5f shows an advanced platform of this type, where heating triggers the release of drugs. Wirelessly delivered power induces the expansion of a degradable polymer matrix (e.g., silks, lipids) that contains drugs (e.g., pTH(1–34), dextran, and doxorubicin). In vitro evaluation of a device that delivers doxorubicin, a well-known anticancer chemotherapy drug, to human tumor cells (HeLa) demonstrates the functionality. Tao et al. reported the use of silk films doped with ampicillin for thermal release in the context of the timed delivery of antibiotics for respiratory and urinary tract infections, meningitis, salmonellosis, and endocarditis. Bioresorbable forms of on-demand, localized drug delivery systems offer an ideal...
scenario for pharmacological treatment of hormone imbalances, malignant cancers, osteoporosis, diabetes, and other diseases.

**CONCLUSIONS**

Insights from the chemistry of dissolvable semiconductor materials underpin emerging, bioreversible classes of electronics, with broad potential utility in consumer, military, industrial, and medical systems. The other materials in these platforms are equally important, and they offer many potential avenues for future development in materials chemistry, where high-performance operation in sensing, actuation and power harvesting, operation with precisely defined lifetimes, and unusual characteristics such as mechanical flexibility are important end goals. Additional opportunities lie in the development of passively, as well as actively, triggered encapsulation and substrate materials. The rich range of possible research directions, from fundamental studies of the chemistry to innovative engineering of the devices and systems, and the important potential applications in biomedicine suggest a bright future for this field.

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